



LM318

LINEAR INTEGRATED CIRCUIT

HIGH SPEED OPERATIONAL AMPLIFIER

DESCRIPTION

The UTC **LM318** is a precision, high speed, high gain operational amplifier that has been specifically designed for use in high slew rate and wide bandwidth applications. Unlike many wideband amplifiers, the UTC **LM318** is unity-gain stable since it has internal circuitry for frequency compensation. However, external components may be added for compensation to achieve optimum performance.

When used in inverting applications, feed-forward compensation can be used to achieve slew rate in excess of 150V/ μ s and almost double the bandwidth. For greater stability, using overcompensation with the amplifier is possible if maximum bandwidth is not needed. In general, by adding a single capacitor can reduce the settling time for 0.1% error band to under 1 μ s.

The typical applications of UTC **LM318** include A/D converters, fast integrator, oscillators, active filters, sample and hold circuits, or general purpose amplifiers.

FEATURES

- * Unit gain stable (internal frequency compensation)
- * 4mV typical input offset voltage
- * 30nA typical input offset current
- * Input bias current of 250nA (maximum)
- * 15MHz bandwidth (small signal)
- * 50V/ μ s slew rate (guarantee)
- * Operates voltages of \pm 5V to \pm 20V
- * Overload protection for Input and output
- * Same pin assignment as general-purpose op amps

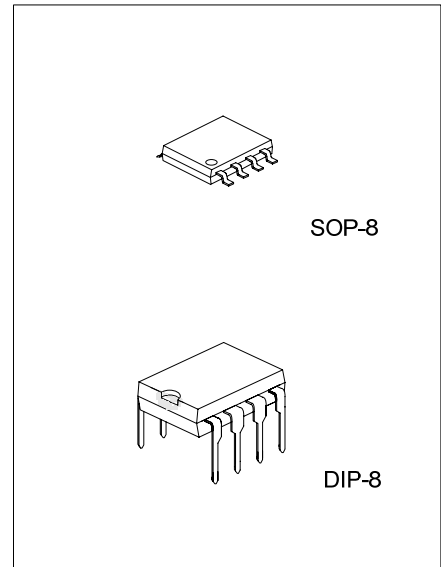
ORDERING INFORMATION

Order Number		Package	Packing
Normal	Lead Free Plating		
LM318-D08-T	LM318L-D08-T	DIP-8	Tube
LM318-S08-R	LM318L-S08-R	SOP-8	Tape Reel
LM318-S08-T	LM318L-S08-T	SOP-8	Tube

LM318L-D08-T

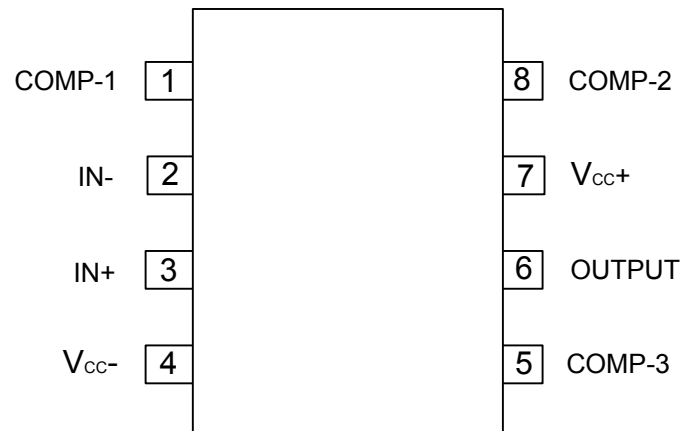
(1)Packing Type
(2)Package Type
(3)Lead Plating

(1) T: Tube, R: Tape Reel
(2) S08: SOP-8, D08: DIP-8
(3) L: Lead Free Plating, Blank: Pb/Sn

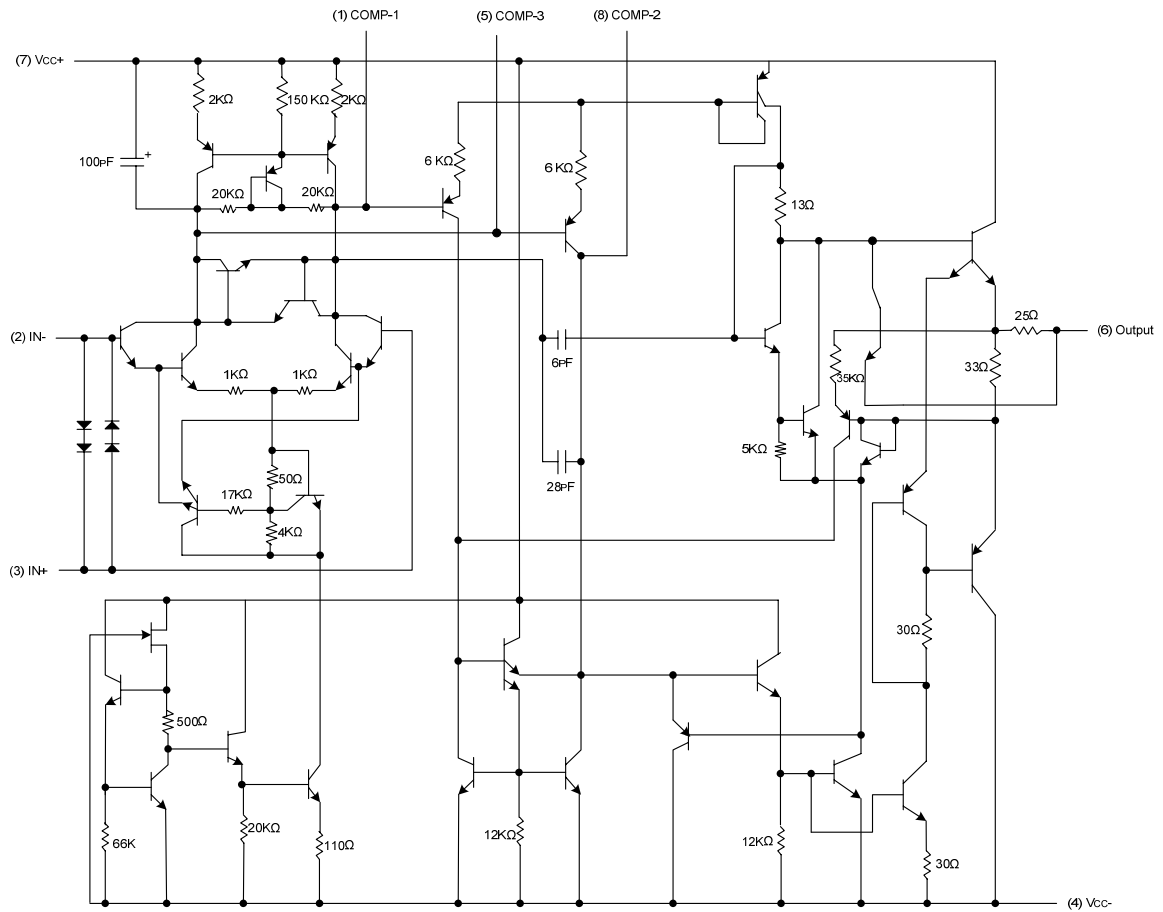


*Pb-free plating product number: LM318L

■ PIN CONFIGURATIONS



■ SCHEMATIC DIAGRAM



■ ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	RATINGS	UNIT
Supply Voltage	V_{CC+}	+20	V
Supply Voltage	V_{CC-}	-20	V
Input Voltage (Note 2)	V_{IN}	± 15	V
Differential Input Current (Note 3)	$I_{I(DIFF)}$	± 10	mA
Power Dissipation	P_D	500	mW
Output Short-Circuit Duration		Continuous	
Maximum Junction Temperature	T_J	110	$^{\circ}\text{C}$
Operating Temperature Range	T_{OPR}	0 ~ +70	$^{\circ}\text{C}$
Storage Temperature Range	T_{STG}	-65 ~ +150	$^{\circ}\text{C}$

Note: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

2. For supply voltage less than $\pm 15\text{V}$, the absolute maximum input voltage is equal to the supply voltage.

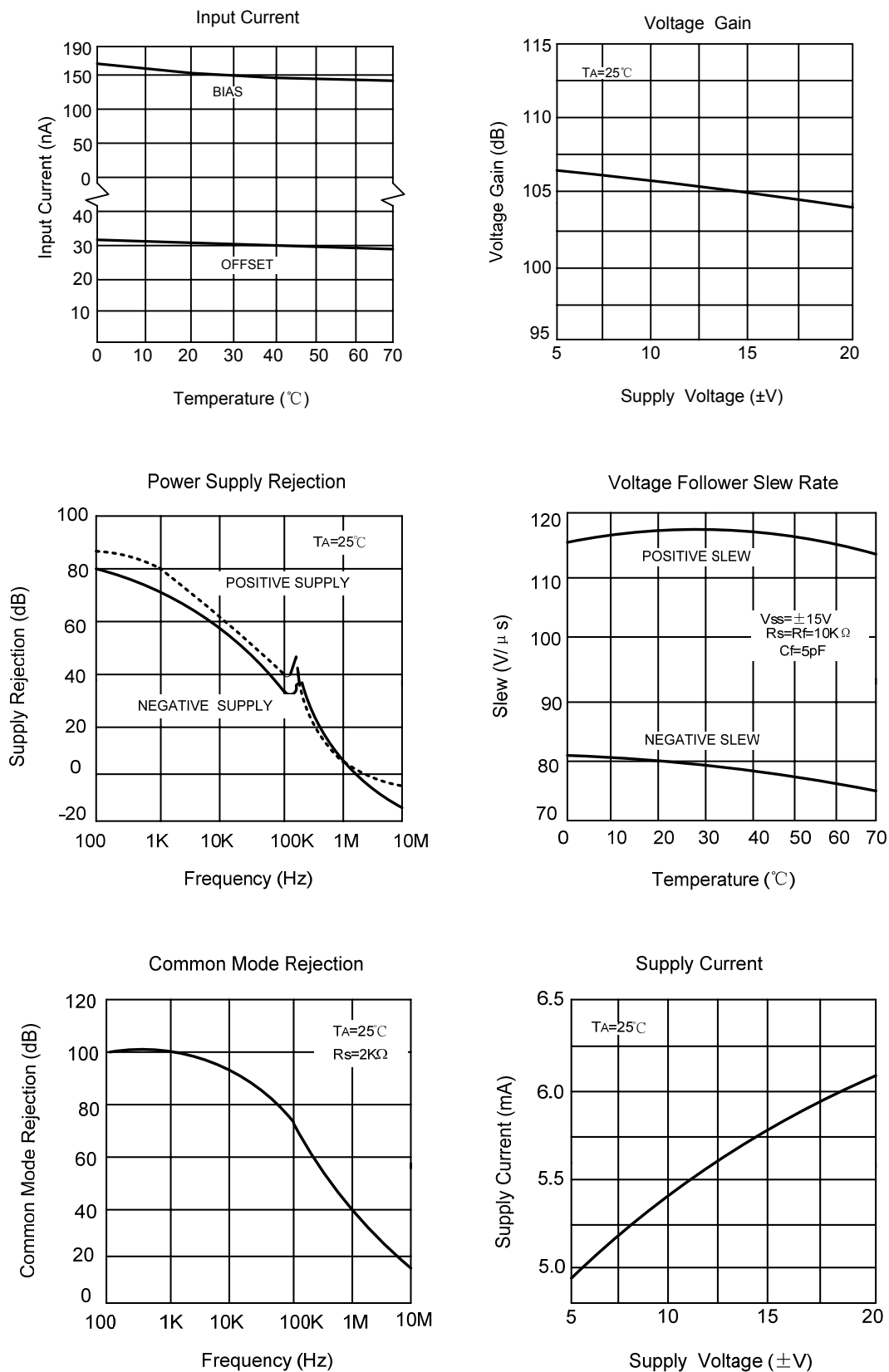
3. The inputs are shunted with two opposite-facing base-emitter diodes for over voltage protection. Therefore, excessive current flows if a differential input voltage in excess of 1V is applied between the inputs unless some limiting resistance is used.

■ ELECTRICAL CHARACTERISTICS ($\pm 5\text{V} \leq V_{CC} \leq \pm 20\text{V}$, $0^{\circ}\text{C} \leq T_A \leq +70^{\circ}\text{C}$, unless other specifics)

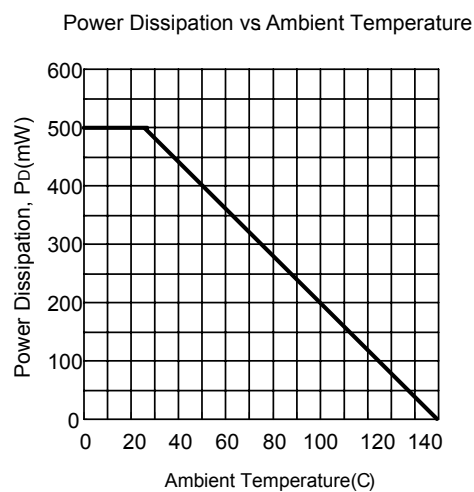
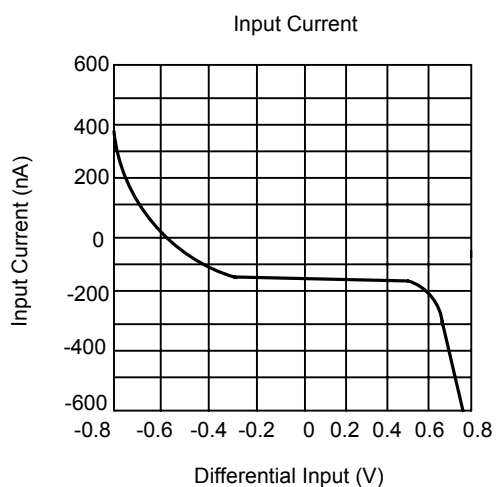
PARAMETER	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
Input Voltage Range	V_{IN}	$V_{CC} = \pm 15\text{V}$	± 11.5			V
Output Voltage Swing	V_{OUT}	$V_{CC} = \pm 15\text{V}$, $R_L = 2\text{K}\Omega$	± 12	± 13		V
Input Offset Voltage	$V_{I(OFF)}$	$T_A = 25^{\circ}\text{C}$		4	10	mV
					15	mV
Large Signal Voltage Gain	G_V	$T_A = 25^{\circ}\text{C}$, $V_{CC} = \pm 15\text{V}$ $V_{OUT} = \pm 10\text{V}$, $R_L \geq 2\text{K}\Omega$	25	200		V/mV
		$V_{CC} = \pm 15\text{V}$, $V_{OUT} = \pm 10\text{V}$, $R_L \geq 2\text{K}\Omega$	20			V/mV
Input Offset Current	$I_{I(OFF)}$	$T_A = 25^{\circ}\text{C}$		30	200	nA
					300	nA
Input Bias Current	$I_{I(BIAS)}$	$T_A = 25^{\circ}\text{C}$		150	500	nA
					750	nA
Supply Current	I_{SS}	$T_A = 25^{\circ}\text{C}$		5	10	mA
Input Resistance	R_S	$T_A = 25^{\circ}\text{C}$	0.5	3		$\text{M}\Omega$
Slew Rate	SR	$T_A = 25^{\circ}\text{C}$, $V_{CC} = \pm 15\text{V}$, $G_V = 1$	50	70		V/ μs
Small Signal Bandwidth	SB_W	$T_A = 25^{\circ}\text{C}$, $V_{CC} = \pm 15\text{V}$		15		MHz
Common Mode Rejection Ratio	CMRR		70	100		dB
Supply Voltage Rejection Ratio	SVRR		65	80		dB

Note: These power supplies must be bypassed with 0.1 μF (or larger) disc ceramic capacitor within an inch of the device.

■ TYPICAL CHARACTERISTICS



■ TYPICAL CHARACTERISTICS(Cont.)



UTC assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all UTC products described or contained herein. UTC products are not designed for use in life support appliances, devices or systems where malfunction of these products can be reasonably expected to result in personal injury. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner. The information presented in this document does not form part of any quotation or contract, is believed to be accurate and reliable and may be changed without notice.